

BC546A/B/C - BC547A/B/C-BC548A/B/C NPN SILICON AMPLIFIER TRANSISTOR

Features

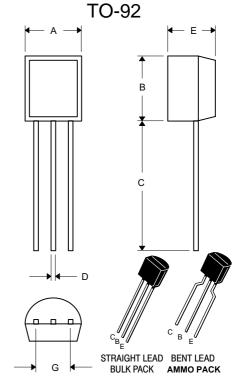
- Lead Free Finish/RoHS Compliant ("P" Suffix designates RoHS Compliant. See ordering information)
- Through Hole Package
- 150°C Junction Temperature
- Epoxy meets UL 94 V-0 flammability rating
- Moisure Sensitivity Level 1
- Halogen free available upon request by adding suffix "-HF"

Mechanical Data

Case: TO-92, Molded Plastic

Polarity:indicated as below





DIMENSIONS								
	INCHES		MM					
DIM	MIN	MAX	MIN	MAX	NOTE			
Α	.175	.185	4.45	4.70				
В	.175	.185	4.45	4.70				
С	.500		12.70					
D	.016	.020	0.41	0.63				
Е	.135	.145	3.43	3.68				
G	.095	.105	2.42	2.67	Straight Lead			
٥	.173	.220	4.40	5.60	Bent Lead			

^{*} For ammo packing detailed specification, click here to visit our website of product packaging for details.

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

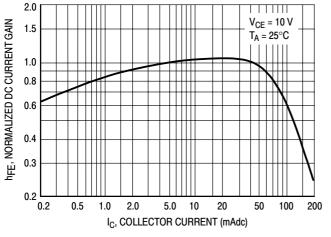
Charateristic	Symbol	Value	Unit
Collector-Emitter Voltage BC546		65	
BC547	V _{CEO}	45	V
BC548		30	
Collector-Base Voltage BC546		80	
BC547	V_{CBO}	50	V
BC548		30	
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current(DC)	I _C	100	mA
D D: : :: 07 0500	P _d	625	mW
Power Dissipation@T _A =25°C	' d	5.0	mW/°C
D D' : " OT 0500	Р	1.5	W
Power Dissipation@T _C =25°C P _d		12	mW/°C
Thermal Resistance, Junction to	R ₀ JA	200	°CW
Ambient Air	UUA		5/11
Thermal Resistance, Junction to	R ₀ JC	83.3	°CW
Case	.,000		C/VV
Operating & Storage Temperature	T _i , T _{STG}	-55~150	°C



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage (I _C = 1.0 mA, I _B = 0)	BC546 BC547 BC548	V _(BR) CEO	65 45 30	_ _ _	_ _ _	V
Collector–Base Breakdown Voltage (I _C = 100 μAdc)	BC546 BC547 BC548	V _{(BR)CBO}	80 50 30	_ _ _	_ _ _	V
Emitter–Base Breakdown Voltage ($I_E = 10 \mu A, I_C = 0$)	BC546 BC547 BC548	V _{(BR)EBO}	6.0 6.0 6.0	_ _ _	_ _ _	V
ON CHARACTERISTICS						
DC Current Gain (I _C = 10 μ A, V _{CE} = 5.0 V)	BC546A/547A/548A BC546B/547B/548B BC546C/547C/548C	h _{FE}	_ _ _	90 150 270	_ _ _	_
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546A/547A/548A BC546B/547B/548B BC546C/547C/548C		110 200 420	180 290 520	220 450 800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546A/547A/548A BC546B/547B/548B BC546C/547C/548C		_ _ _	120 180 300	_ _ _	
Collector–Emitter Saturation Voltage (I _C = 100 mA, I _B = 5.0 mA)		V _{CE(sat)}	_		0.3	V
Base–Emitter Saturation Voltage (Ic = 100 mA, IB = 5.0 mA)		V _{BE(sat)}	_	_	1.0	V
Base–Emitter On Voltage ($I_C = 2.0$ mA, $V_{CE} = 5.0$ V) ($I_C = 10$ mA, $V_{CE} = 5.0$ V)		V _{BE(on)}	0.55 —	_	0.7 0.77	V
SMALL-SIGNAL CHARACTERISTICS						
Current–Gain — Bandwidth Product $(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz})$	BC546 BC547 BC548	f _T	150 150 150	300 300 300	_ _ _	MHz
Output Capacitance ($V_{CB} = 10 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)		C _{obo}	_	1.7	4.5	pF
Input Capacitance (V _{EB} = 0.5 V, I _C = 0, f = 1.0 MHz)		C _{ibo}	_	10	_	pF
Small–Signal Current Gain (I _C = 2.0 mA, V _{CE} = 5.0 V, f = 1.0 kHz)		h _{fe}				_
	BC546A/547A/548A BC546B/547B/548B BC546C/547C/548C		125 240 450	220 330 600	260 500 900	
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2 k Ω , f = 1.0 kHz, Δ f = 200 Hz)	BC546 BC547 BC548	NF	_ _ _	2.0 2.0 2.0	10 10 10	dB

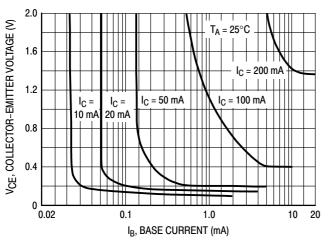




1.0 $T_A = 25^{\circ}C$ 0.9 0.8 V_{BE(sat)} @ I_C/I_B 0.7 V, VOLTAGE (VOLTS) V_{BE(on)} @ V_{CE} 0.6 0.5 0.4 0.3 0.2 $V_{CE(sat)} @ I_C/I_B = 10$ 0.1 0.1 $0.2\;0.3\ \ \, 0.5\;0.7\;1.0$ 2.0 3.0 5.0 7.0 10 20 30 50 70 100 I_C, COLLECTOR CURRENT (mAdc)

Figure 1. Normalized DC Current Gain

Figure 2. "Saturation" and "On" Voltages



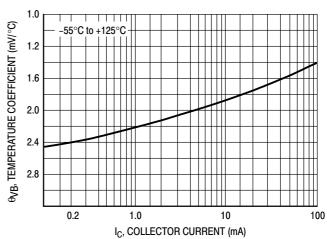
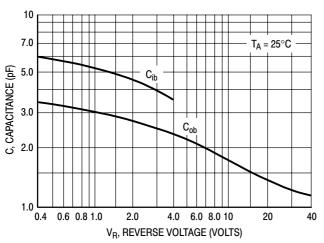


Figure 3. Collector Saturation Region

Figure 4. Base-Emitter Temperature Coefficient



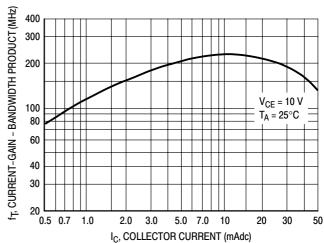


Figure 5. Capacitances

Figure 6. Current-Gain - Bandwidth Product

BC547/BC548



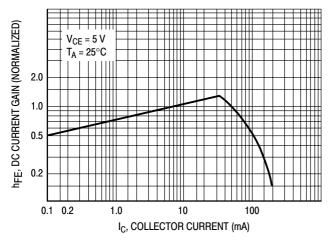


Figure 7. DC Current Gain

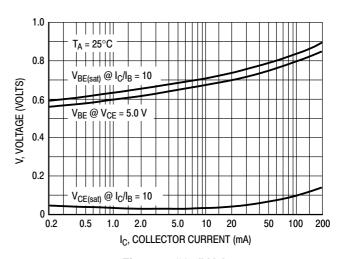


Figure 8. "On" Voltage

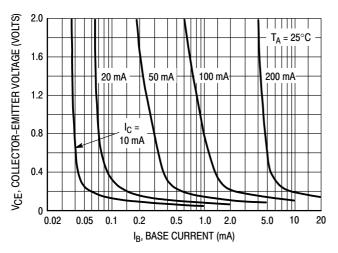


Figure 9. Collector Saturation Region

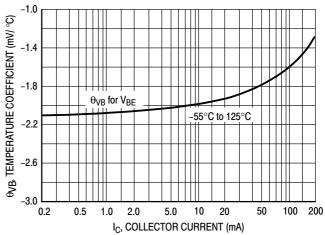


Figure 10. Base-Emitter Temperature Coefficient

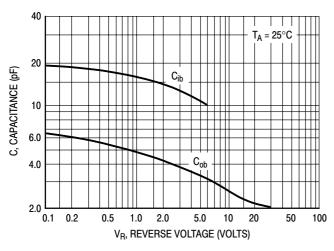


Figure 11. Capacitance

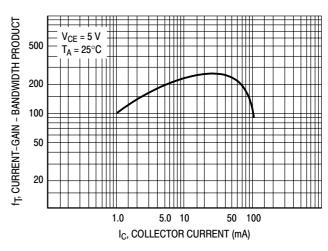


Figure 12. Current-Gain - Bandwidth Product

BC546